Fast Recovery Diodes (Stud Version), 40 A/70 A/85 A

DO-203AB (DO-5)

FEATURES

- Short reverse recovery time
- Low stored charge
- Wide current range
- Excellent surge capabilities
- Stud cathode and stud anode versions
- Types up to 100 V_{RRM}
- Compliant to RoHS directive 2002/95/EC

RoHS COMPLIANT

TYPICAL APPLICATIONS

- DC power supplies
- Inverters
- Converters
- Choppers
- Ultrasonic systems
- Freewheeling diodes

PRODUCT SUMMARY	
$I_{F(AV)}$	40 A/70 A/85 A

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	40HFL	70HFL	85HFL	UNITS
$I_{F(AV)}$		40	70	85	A
	Maximum T_C	85	85	85	°C
I_{FSM}	50 Hz	400	700	1100	A
	60 Hz	420	730	1151	
I^2t	50 Hz	800	2450	6050	A^2s
	60 Hz	730	2240	5523	
$I^2\sqrt{t}$		11 300	34 650	85 560	$I^2\sqrt{s}$
V_{RRM}	Range	100 to 1000			V
t_{rr}		See Recovery Characteristics table			ns
T_J	Range	- 40 to 125			°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER [1]	V_{RRM}, MAXIMUM PEAK REPETITIVE REVERSE VOLTAGE T_J = - 40 °C TO 125 °C V	V_{RSM}, MAXIMUM PEAK NON-REPETITIVE REVERSE VOLTAGE T_J = 25 °C TO 125 °C V	I_{FM}, MAXIMUM PEAK REVERSE CURRENT AT RATED V_{RRM} mA	
			T_J = 25 °C	T_J = 125 °C
40HFL10S02, 40HFL10S05, 40HFL10S10	100	150	0.1	10
40HFL20S02, 40HFL20S05, 40HFL20S10	200	300		
40HFL40S02, 40HFL40S05, 40HFL40S10	400	500		
40HFL60S02, 40HFL60S05, 40HFL60S10	600	700		
40HFL80S05, 40HFL80S10	800	900		
40HFL100S05, 40HFL100S10	1000	1100		
70HFL10S02, 70HFL10S05, 70HFL10S10	100	150	0.1	15
70HFL20S02, 70HFL20S05, 70HFL20S10	200	300		
70HFL40S02, 70HFL40S05, 70HFL40S10	400	500		
70HFL60S02, 70HFL60S05, 70HFL60S10	600	700		
70HFL80S05, 70HFL80S10	800	900		
70HFL100S05, 70HFL100S10	1000	1100		
85HFL10S02, 85HFL10S05, 85HFL10S10	100	150	0.1	20
85HFL20S02, 85HFL20S05, 85HFL20S10	200	300		
85HFL40S02, 85HFL40S05, 85HFL40S10	400	500		
85HFL60S02, 85HFL60S05, 85HFL60S10	600	700		
85HFL80S05, 85HFL80S10	800	900		
85HFL100S05, 85HFL100S10	1000	1100		

Note

[1] Types listed are cathode case, for anode case add “R” to code, i.e. 40HFLR20S02, 85HFLR100S05 etc.

FORWARD CONDUCTION

PARAMETER	SYMBOL	TEST CONDITIONS		40HFL	70HFL	85HFL	UNITS
Maximum average forward current at maximum case temperature	$I_{F(AV)}$	180° conduction, half sine wave		40	70	85	A
				75			°C
Maximum RMS forward current	$I_{F(RMS)}$			63	110	134	A
Maximum peak repetitive forward current	I_{FRM}	Sinusoidal half wave, 30° conduction		220	380	470	A
Maximum peak, one-cycle non-repetitive forward current	I_{FSM}	t = 10 ms	Sinusoidal half wave, 100 % V_{RRM} reapplied, initial $T_J = T_J$ maximum	400	700	1100	A
		t = 8.3 ms		420	730	1151	
		t = 10 ms	Sinusoidal half wave, no voltage reapplied, initial $T_J = T_J$ maximum	475	830	1308	
		t = 8.3 ms		500	870	1369	
Maximum I^2t for fusing	I^2t	t = 10 ms	100 % V_{RRM} reapplied, initial $T_J = T_J$ maximum	800	2450	6050	A^2s
		t = 8.3 ms		730	2240	5523	
		t = 10 ms	No voltage reapplied, initial $T_J = T_J$ maximum	1130	3460	8556	
		t = 8.3 ms		1030	3160	7810	
Maximum $I^2\sqrt{t}$ for fusing (1)	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied		11 300	34 650	85 560	$A^2\sqrt{s}$
Maximum value of threshold voltage	$V_{F(TO)}$	T_J = 125 °C		1.081	1.085	1.128	V
Maximum value of forward slope resistance	r_F			6.33	3.40	2.11	mΩ
Maximum forward voltage drop	V_{FM}	T_J = 25 °C, $I_{FM} = \pi \times I_{F(AV)}$		1.95	1.85	1.75	V

Note

(1) I^2t for time $t_x = I^2\sqrt{t} \bullet \sqrt{t_x}$

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	40HFL...			70HFL...			85HFL...			UNITS
			S02	S05	S10	S02	S05	S10	S02	S05	S10	
Typical reverse recovery time	t_{rr}	T_J = 25 °C, I_F = 1 A to V_R = 30 V, - dI_F/dt = 100 A/µs	70	180	350	60	150	290	50	120	270	ns
		T_J = 25 °C, - dI_F/dt = 25 A/µs, $I_{FM} = \pi \times$ rated $I_{F(AV)}$	200	500	1000	200	500	1000	200	500	1000	
Typical reverse recovered charge	Q_{rr}	T_J = 25 °C, I_F = 1 A to V_R = 30 V, - dI_F/dt = 100 A/µs	160	750	3100	90	500	1600	70	340	1350	nC
		T_J = 25 °C, - dI_F/dt = 25 A/µs, $I_{FM} = \pi \times$ rated $I_{F(AV)}$	240	1300	6000	240	1300	6000	240	1300	6000	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**40HFL**	**70HFL**	**85HFL**	**UNITS**
Junction operating temperature range	T_J		- 40 to 125			°C
Storage temperature range	T_{Stg}		- 40 to 150			
Maximum thermal resistance, junction to case	R_{thJC}	DC operation	0.60	0.36	0.30	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased	0.25			
Maximum allowable mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on nut (1)	3.4 (30)			N · m (lbf · in)
		Lubricated thread, tighting on nut (1)	2.3 (20)			
		Not lubricated thread, tighting on hexagon (2)	4.2 (37)			
		Lubricated thread, tighting on hexagon (2)	3.2 (28)			
Approximate weight			25			
			0.88			
Case style		JEDEC	DO-203AB (DO-5)			

Notes

(1) Recommended for pass-through holes

(2) Recommended for holed threaded heatsinks

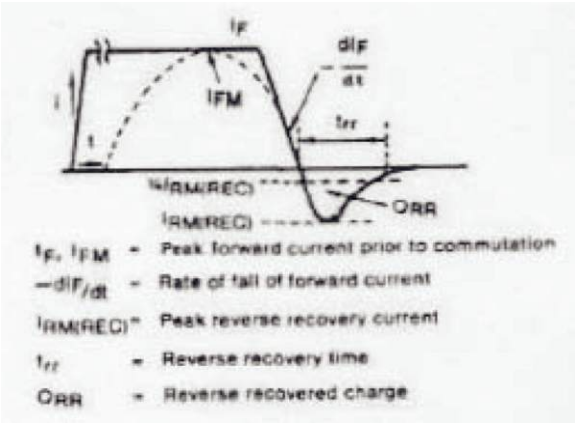


Fig. 1 - Reverse Recovery Time Test Waveform

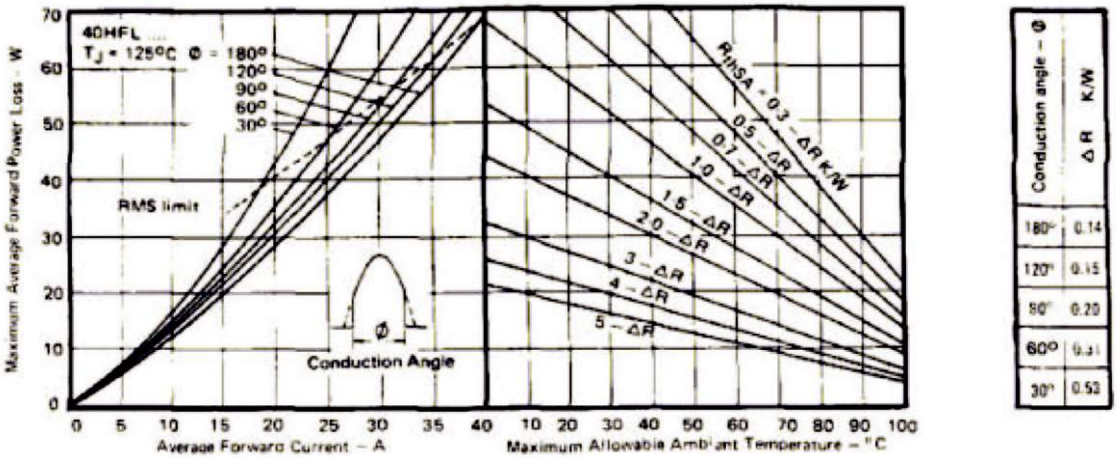
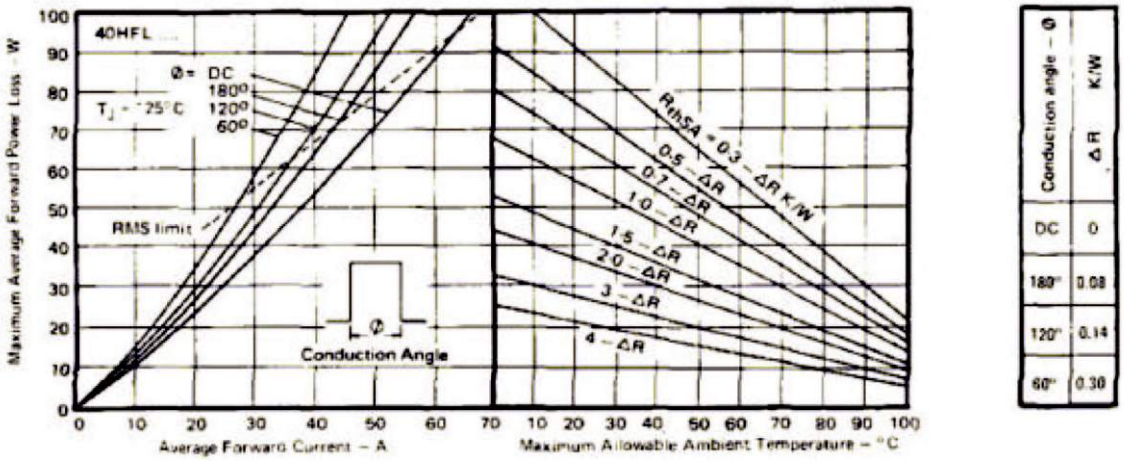
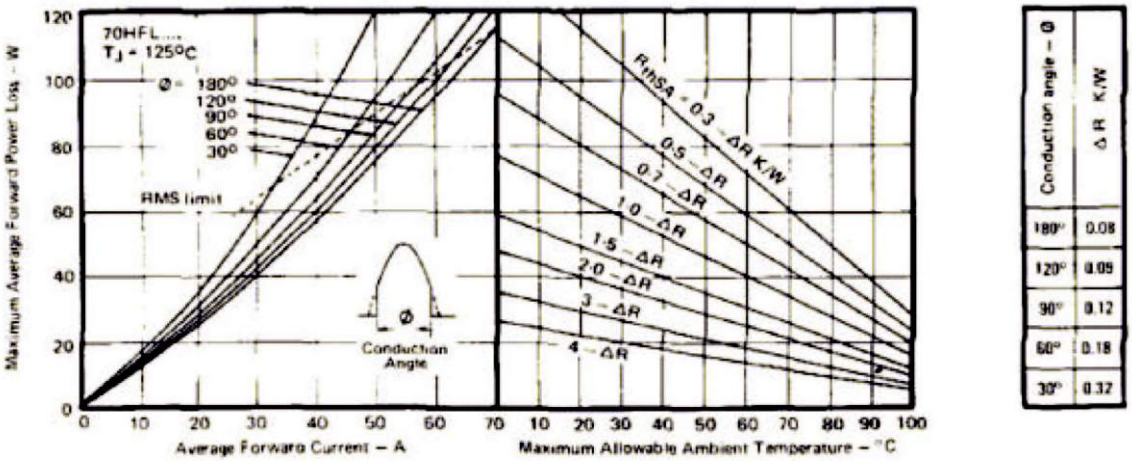


Fig. 2 - Current Rating Nomogram (Sinusoidal Waveforms), 40HFL Series



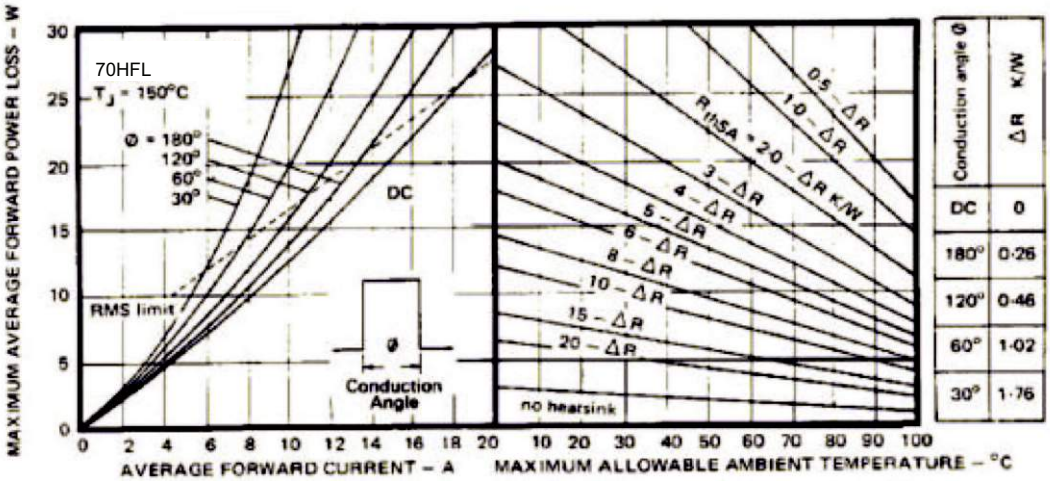
Conduction angle – Ø	ΔR K/W
DC	0
180°	0.08
120°	0.14
60°	0.30

Fig. 3 - Current Rating Nomogram (Rectangular Waveforms), 40HFL Series



Conduction angle – Ø	ΔR K/W
180°	0.08
120°	0.09
90°	0.12
60°	0.18
30°	0.32

Fig. 4 - Current Rating Nomogram (Sinusoidal Waveforms), 70HFL Series



Conduction angle Ø	ΔR K/W
DC	0
180°	0·26
120°	0·46
60°	1·02
30°	1·76

Fig. 5 - Current Rating Nomogram (Rectangular Waveforms), 70HFL Series

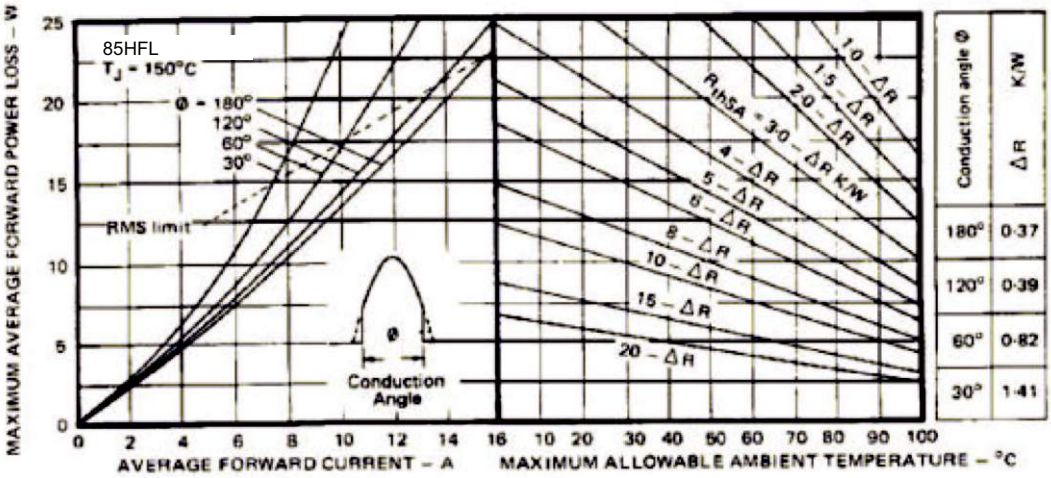


Fig. 6 - Current Rating Nomogram (Sinusoidal Waveforms), 85HFL Series

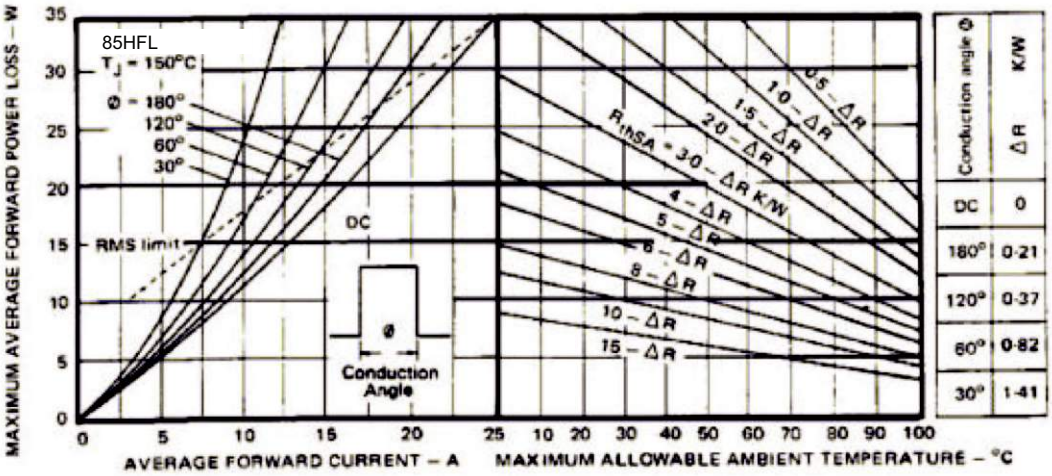


Fig. 7 - Current Rating Nomogram (Rectangular Waveforms), 85HFL Series

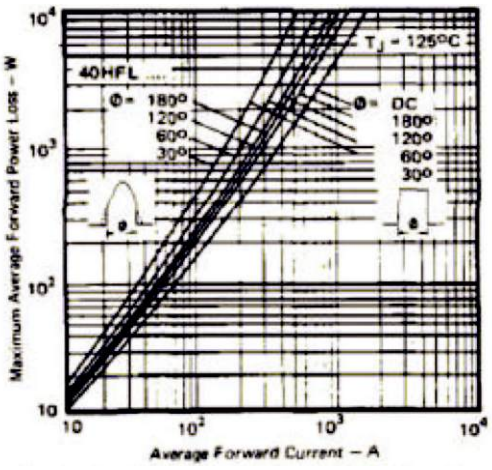


Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 40HFL Series

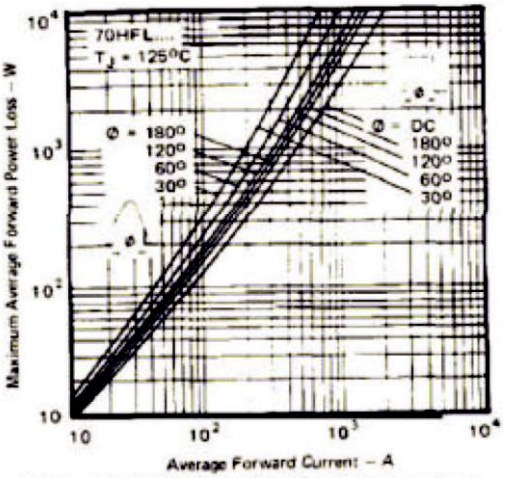


Fig. 9 - Maximum High Level Forward Power Loss vs. Average Forward Current, 70HFL Series

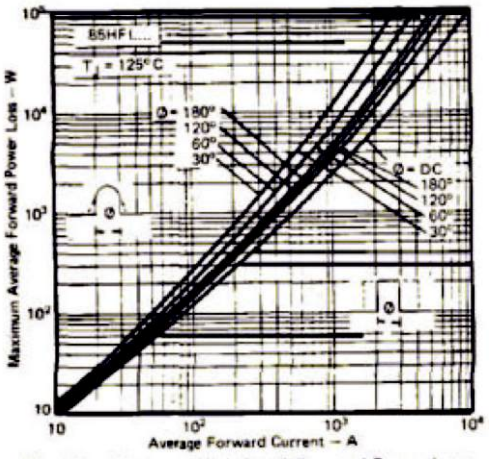


Fig. 10 - Maximum High Level Forward Power Loss vs. Average Forward Current, 85HFL Series

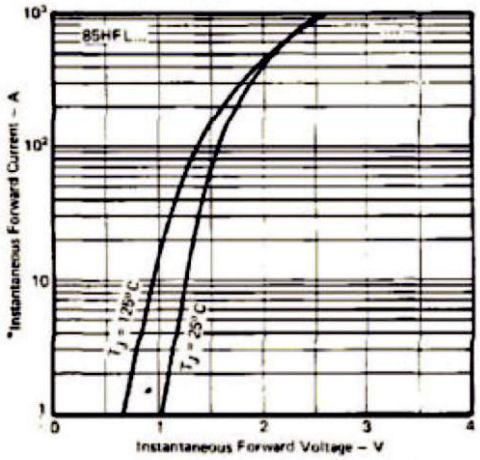


Fig. 13 - Maximum Forward Voltage vs. Forward Current, 85HFL Series

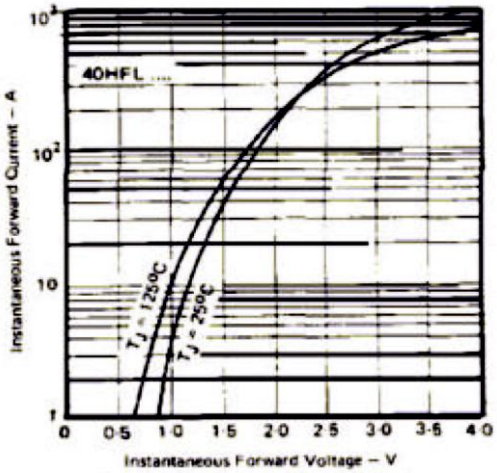


Fig. 11 - Maximum Forward Voltage vs. Forward Current, 40HFL Series

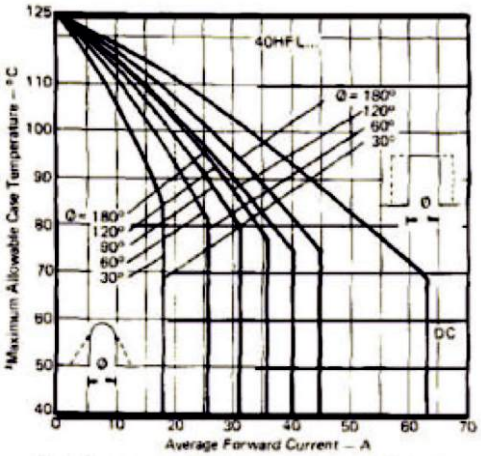


Fig. 14 - Average Forward Current vs. Maximum Allowable Case Temperature, 40HFL Series

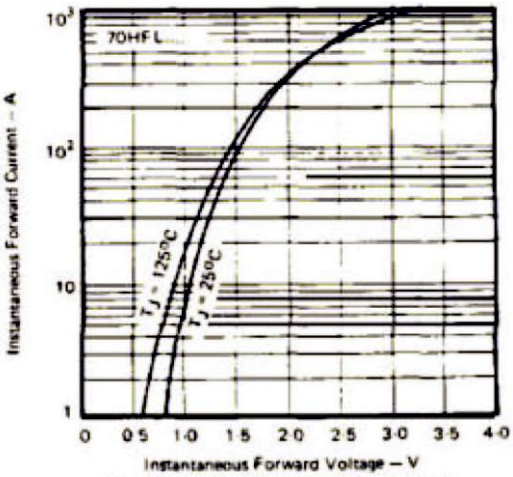


Fig. 12 - Maximum Forward Voltage vs. Forward Current, 70HFL Series

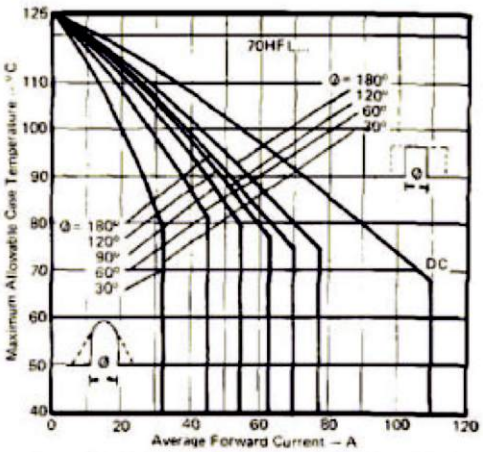


Fig. 15 - Average Forward Current vs. Maximum Allowable Case Temperature, 70HFL Series

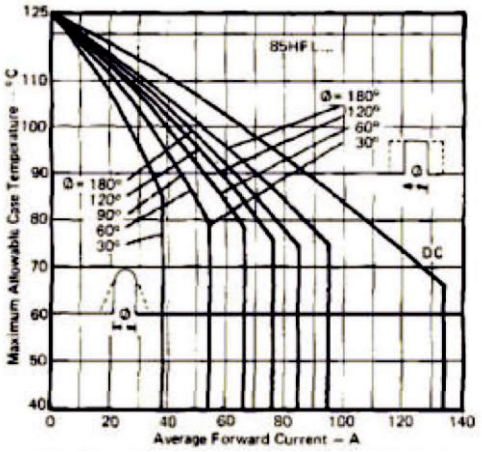


Fig. 16 - Average Forward Current vs. Maximum Allowable Case Temperature, 85HFL Series

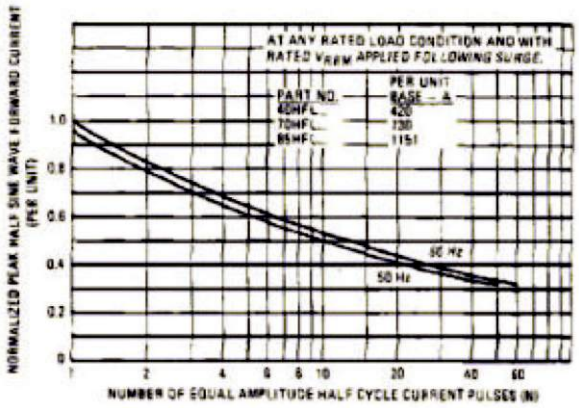


Fig. 17 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, All Series

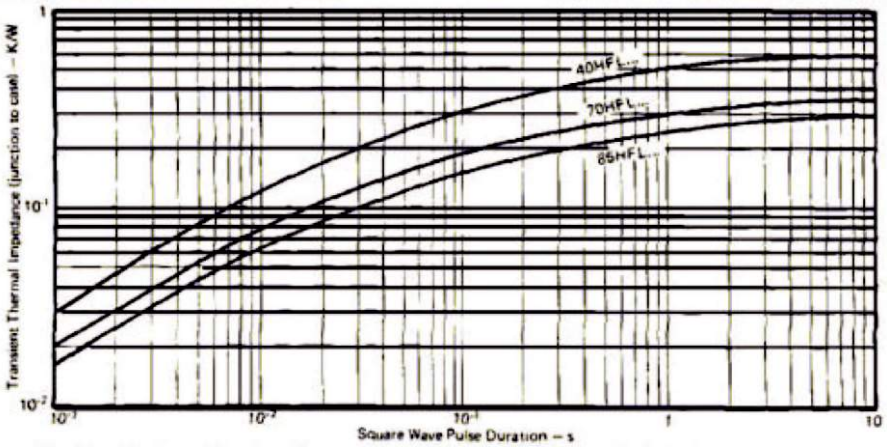


Fig. 18 - Maximum Transient Thermal Impedance, Junction to Case vs. Pulse Duration, All Series

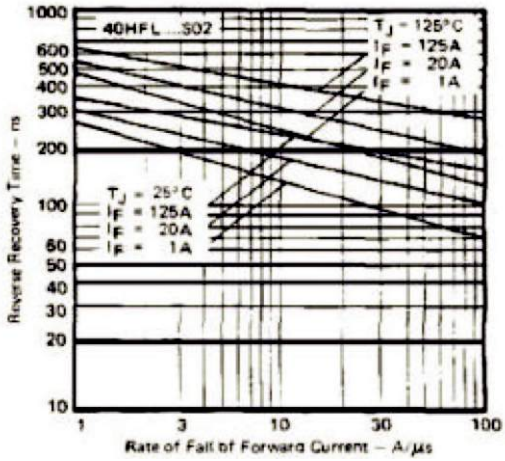


Fig. 19 - Typical Reverse Recovery Time vs. Rate of Fall of Forward Current, 40HFL...S02 Series

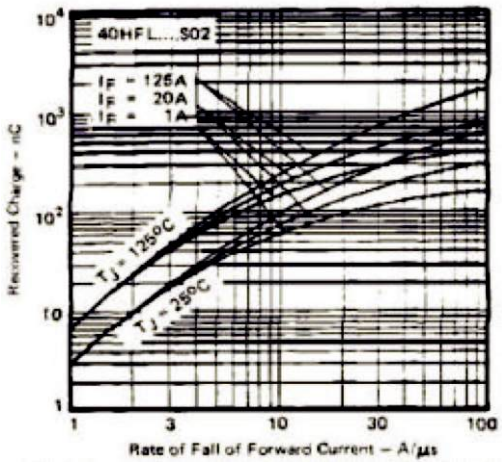


Fig. 20 - Typical Recovered Charge vs. Rate of Fall of Forward Current, 40HFL...S02 Series

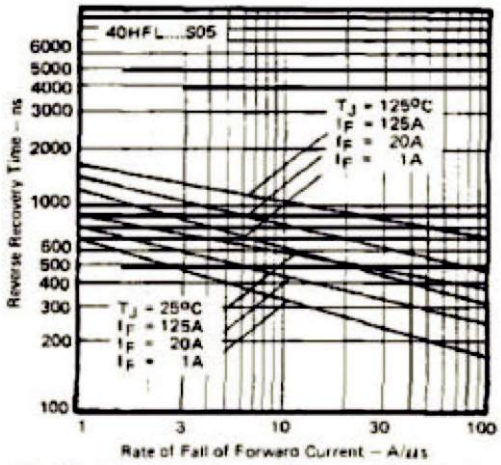


Fig. 21 - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, 40HFL...S05 Series

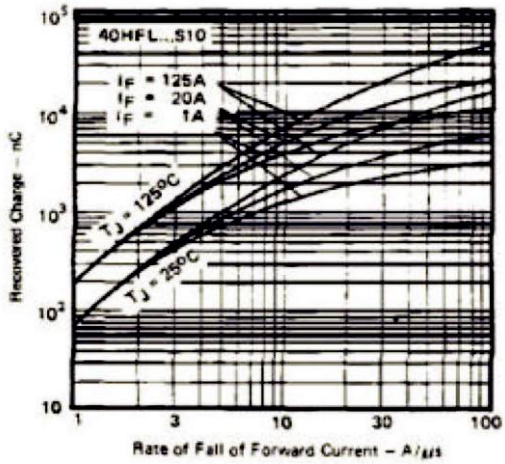


Fig. 24 - Typical Recovered Charge vs.
Rate of Fall of Forward Current, 40HFL...S10 Series

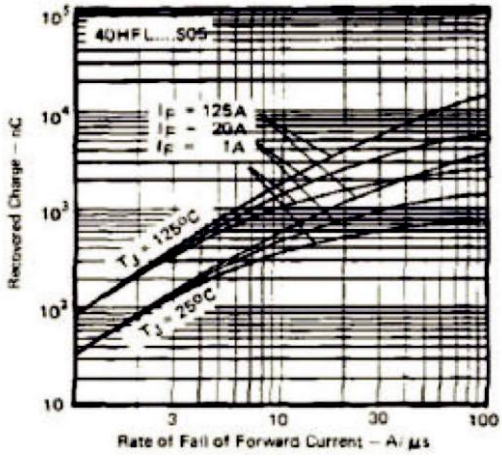


Fig. 22 - Typical Recovered Charge vs.
Rate of Fall of Forward Current, 40HFL...S05 Series

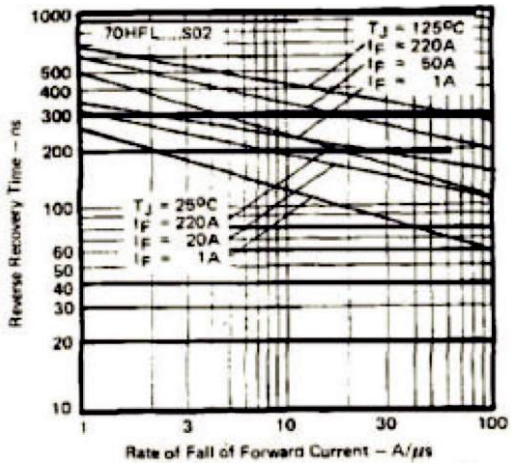


Fig. 25 - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, 70HFL...S02 Series

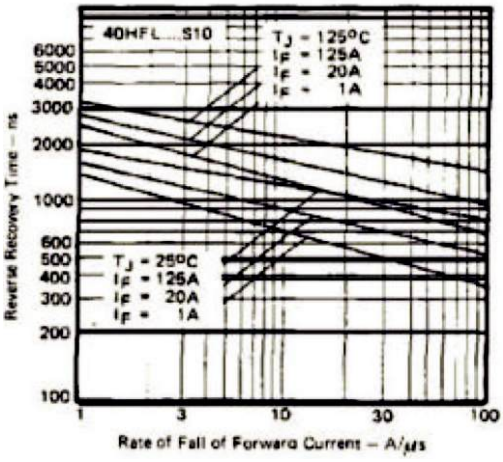


Fig. 23 - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, 40HFL...S10 Series

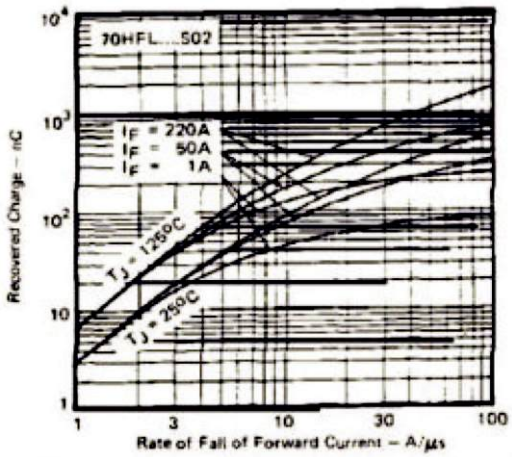


Fig. 26 - Typical Recovered Charge vs.
Rate of Fall of Forward Current, 70HFL...S02 Series

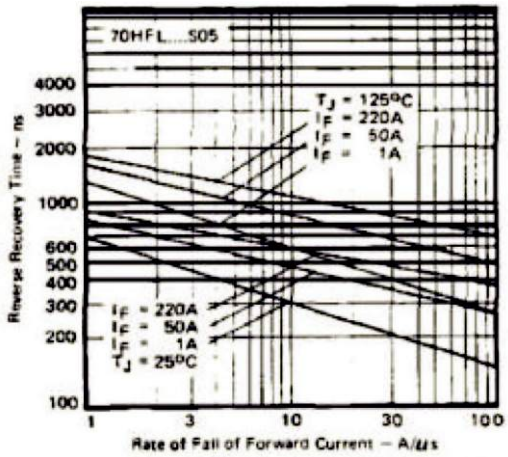


Fig. 27 - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, 70HFL...S05 Series

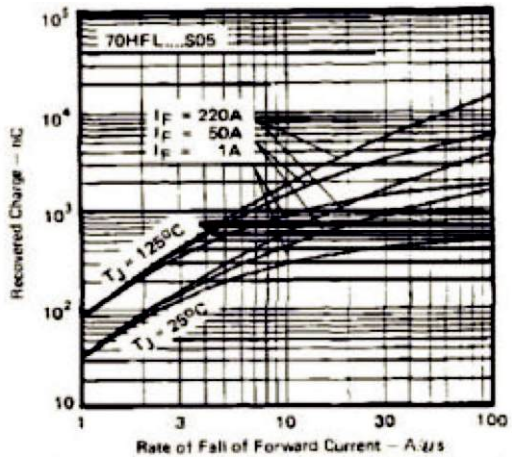


Fig. 28 - Typical Recovered Charge vs.
Rate of Fall of Forward Current, 70HFL...S05 Series

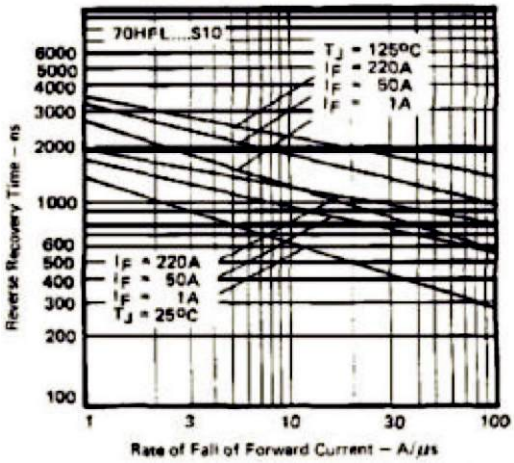


Fig. 29 - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, 70HFL...S10 Series

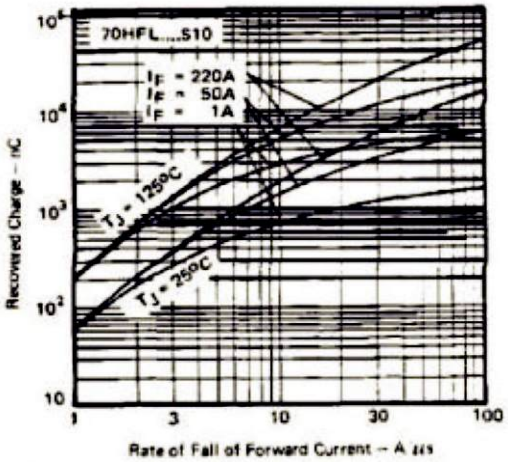


Fig. 30 - Typical Recovered Charge vs.
Rate of Fall of Forward Current, 70HFL...S10 Series

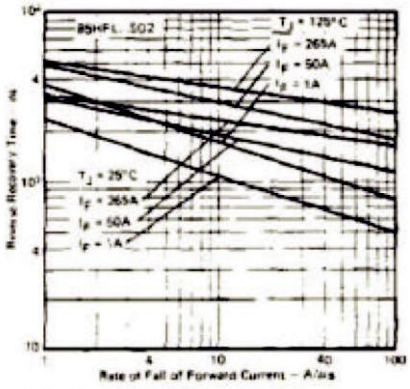


Fig. 31 - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, 85HFL...S02 Series

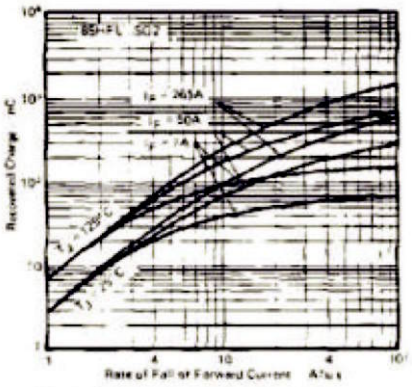


Fig. 32 - Typical Recovered Charge vs.
Rate of Fall of Forward Current, 85HFL...S02 Series

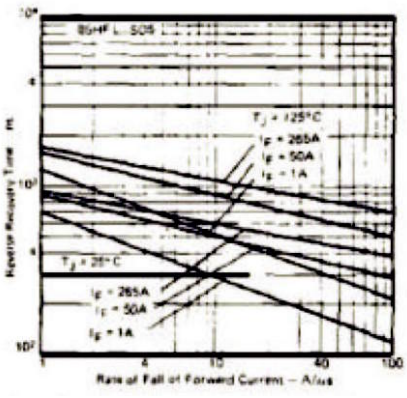


Fig. 33 - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, 85HFL...S05 Series

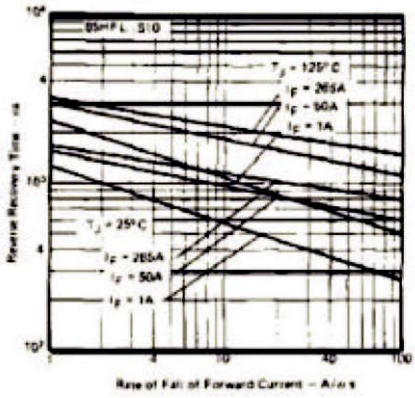


Fig. 35 - Typical Reverse Recovery Time vs.
Rate of Fall of Forward Current, 85HFL...S10 Series

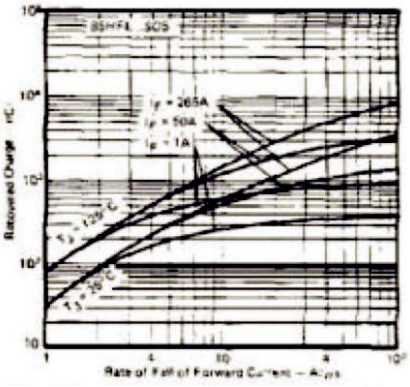


Fig. 34 - Typical Recovered Charge vs.
Rate of Fall of Forward Current, 85HFL...S05 Series

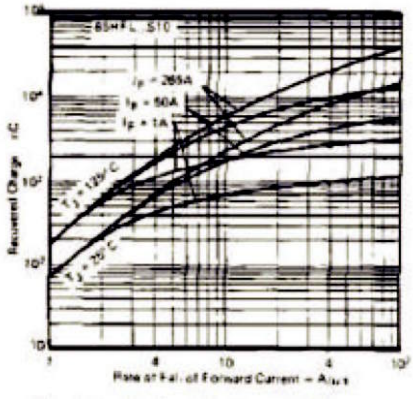
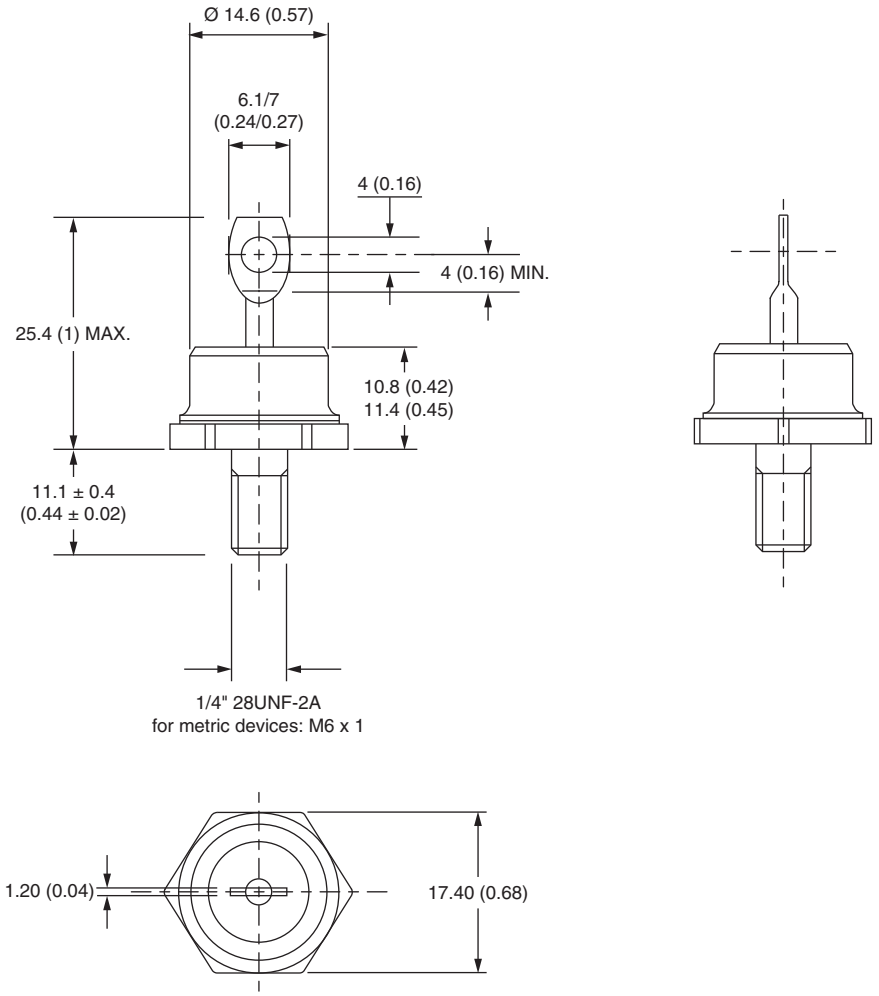


Fig. 36 - Typical Recovered Charge vs.
Rate of Fall of Forward Current, 85HFL...S10 Series

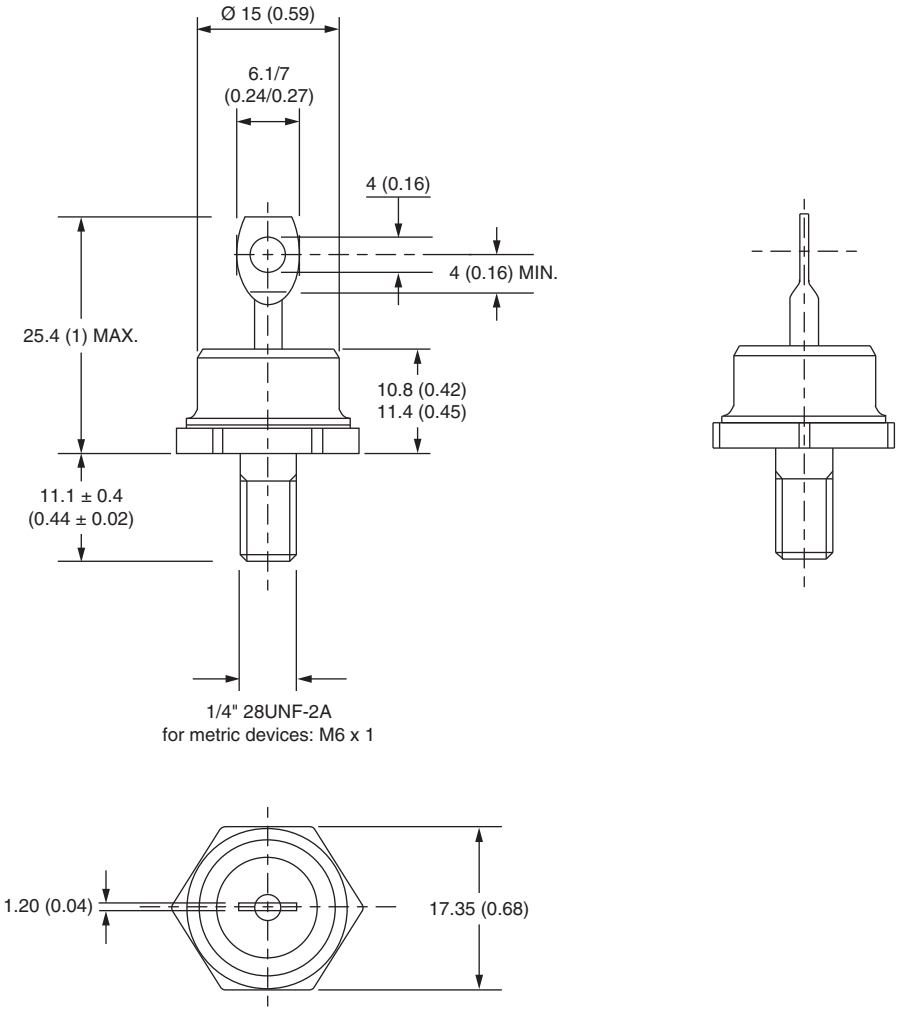
LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95312

DO-203AB (DO-5) for 40HFL, 70HFL and 85HFL

DIMENSIONS FOR 40HFL/70HFL in millimeters (inches)



DIMENSIONS FOR 85HFL in millimeters (inches)



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